L	Hits	Search Text	DB	Time stamp
Number		'		
25	44	((p-type near GaAs near3 substrate) or	USPAT;	2004/05/28
		(p-GaAs near3 substrate)) and pin	US-PGPUB;	15:21
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
26	20	P = 2F = + + + + + + + + + + + + + + + + + +	USPAT;	2004/05/28
		superlattice)	US-PGPUB;	15:19
		•	EPO; JPO;	ŀ
			DERWENT;	·
			IBM_TDB	
27	3008312	p-(ZnSe/ZnTe) near3 superlattice	USPAT;	2004/05/28
	1		US-PGPUB;	15:20
			EPO; JPO;	1
			DERWENT;	
			IBM_TDB	
28	1421	((p-type near GaAs near3 substrate) or	USPAT;	2004/05/28
		(p-GaAs near3 substrate))	US-PGPUB;	15:21
			EPO; JPO;]
			DERWENT;	. 1
	4		IBM_TDB	
29	1421	(p-(ZnSe/ZnTe) near3 superlattice) and	USPAT;	2004/05/28
		(((p-type near GaAs near3 substrate) or	US-PGPUB;	15:21
		(p-GaAs near3 substrate)))	EPO; JPO;	- "
			DERWENT;	
2.0	101		IBM_TDB	
30	101	((p-(ZnSe/ZnTe) near3 superlattice) and	USPAT;	2004/05/28
		(((p-type near GaAs near3 substrate) or	US-PGPUB;	15:22
		(p-GaAs near3 substrate)))) and	EPO; JPO;	
		(photodiode or photodetector)	DERWENT;	·
			IBM TDB	